



PJM3401PSC

P-Channel Enhancement Mode Power MOSFET

Product Summary

- $V_{DS} = -30V, I_D = -4.4A$
- $R_{DS(on)} < 60m\Omega @ V_{GS} = -10V$
- $R_{DS(on)} < 78m\Omega @ V_{GS} = -4.5V$
- $R_{DS(on)} < 78m\Omega @ V_{GS} = -2.5V$

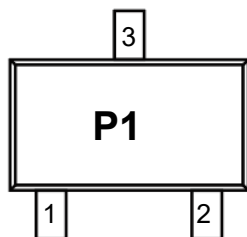
Features

- Advanced Trench Technology
- RoHS and Reach Compliant
- Halogen and Antimony Free
- Moisture Sensitivity Level 3

Application

- Load Switch
- PWM Application

Marking Code



Absolute Maximum Ratings

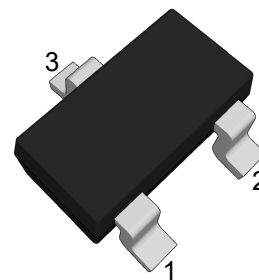
(Ta=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$-V_{DS}$	30	V
Gate-Source Voltage	V_{GS}	± 12	V
Drain Current-Continuous	$-I_D$	4.4	A
Drain Current-Pulsed ^{Note1}	$-I_{DM}$	20	A
Maximum Power Dissipation	P_D	1.25	W
Junction Temperature	T_J	150	°C
Storage Temperature Range	T_{STG}	-55 to +150	°C

Thermal Characteristics

Thermal Resistance, Junction-to-Ambient ^{Note2}	$R_{\theta JA}$	100	°C/W
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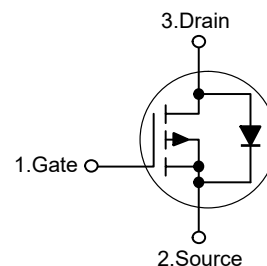
SOT-23-3



(Top View)

Pin	Description
1	Gate
2	Source
3	Drain

Schematic Diagram





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Electrical Characteristics

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	-V _{(BR)DSS}	V _{GS} =0V,I _D =-250μA	30	--	--	V
Zero Gate Voltage Drain Current	-I _{DSS}	V _{DS} =-30V,V _{GS} =0V	--	--	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±12V,V _{DS} =0V	--	--	±100	nA
Gate Threshold Voltage ^{Note3}	-V _{GS(th)}	V _{DS} =V _{GS} ,I _D =-250μA	0.5	0.8	1.4	V
Drain-Source On-Resistance ^{Note3}	R _{DS(on)}	V _{GS} =-10V,I _D =-4.4A	--	41	50	mΩ
		V _{GS} =-4.5V,I _D =-4A	--	45	65	mΩ
		V _{GS} =-2.5V,I _D =-1A	--	55	90	mΩ
Forward Transconductance ^{Note3}	g _{FS}	V _{DS} =-5V,I _D =-2A	--	9.5	--	S
Dynamic Characteristics						
Input Capacitance	C _{iss}	V _{DS} =-15V,V _{GS} =0V,f=1MHz	--	780	--	pF
Output Capacitance	C _{oss}		--	65	--	pF
Reverse Transfer Capacitance	C _{rss}		--	52	--	pF
Gate Resisitance	R _g	V _{DS} =0V,V _{GS} =0V,f=1MHz	--	13	--	Ω
Total Gate Charge	Q _g	V _{DS} =-15V,I _D = -4.2A, V _{GS} =0~ -4.5V	--	8	--	nC
Gate-Source Charge	Q _{gs}		--	1.8	--	nC
Gate-Drain Charge	Q _{gd}		--	2.7	--	nC
Switching Characteristics						
Turn-on Delay Time	t _{d(on)}	V _{DD} =-15V,I _D =-4.2A, V _{GS} =-10V,R _{GEN} =3Ω	--	7	--	nS
Turn-on Rise Time	t _r		--	3	--	nS
Turn-off Delay Time	t _{d(off)}		--	30	--	nS
Turn-off Fall Time	t _f		--	12	--	nS
Source-Drain Diode Characteristics						
Diode Forward Voltage ^{Note3}	-V _{SD}	V _{GS} =0V,I _S =-4.4A	--	--	1.2	V
Diode Forward Current ^{Note2}	-I _S		--	--	4.4	A

Note: 1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \leq 10$ sec.

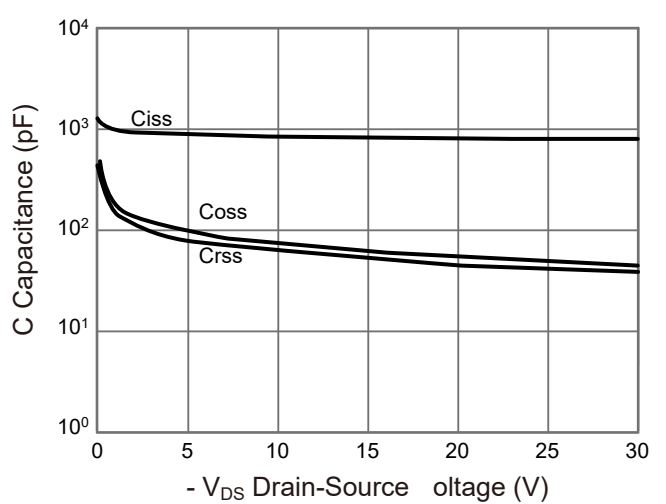
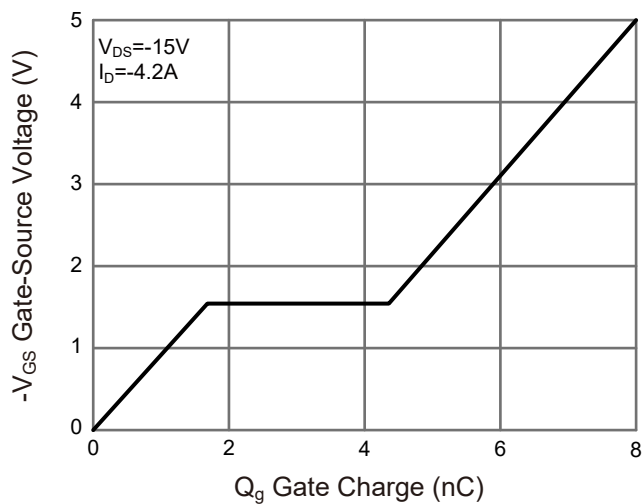
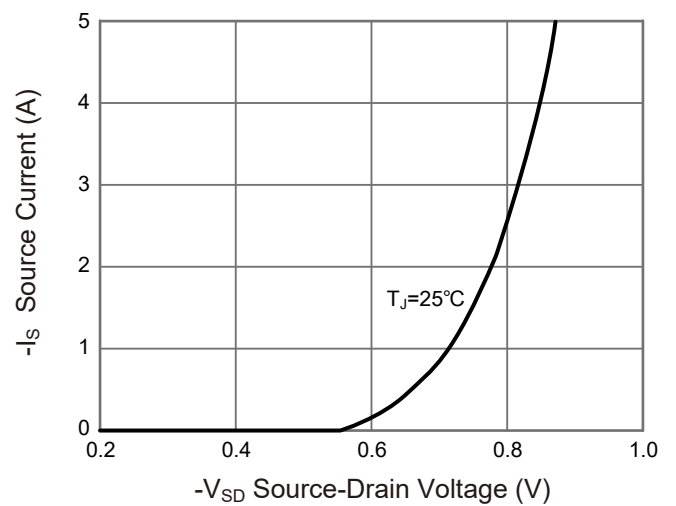
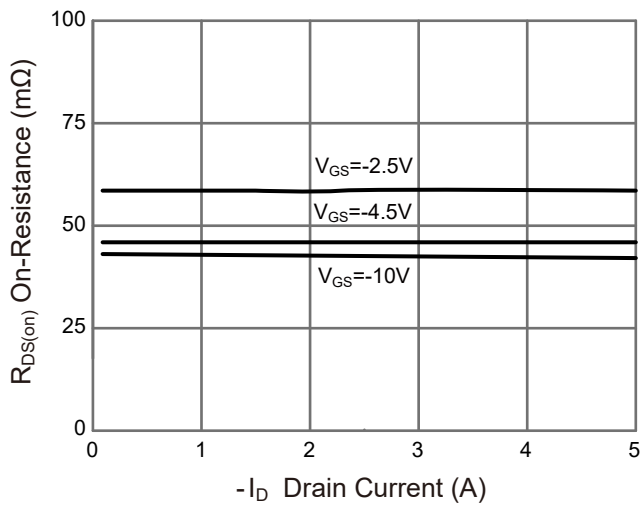
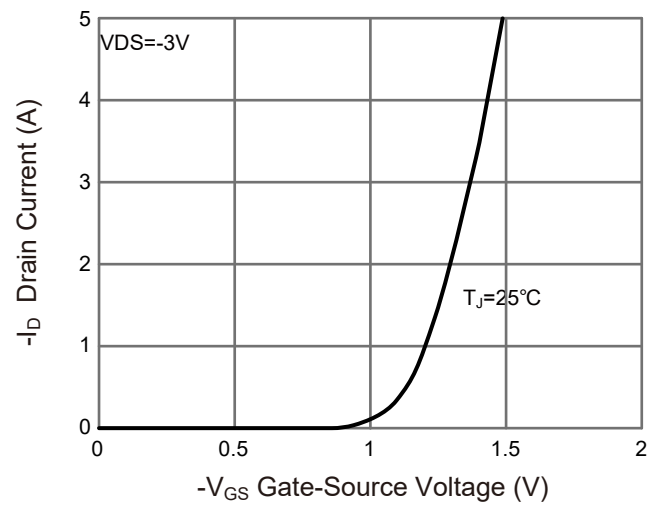
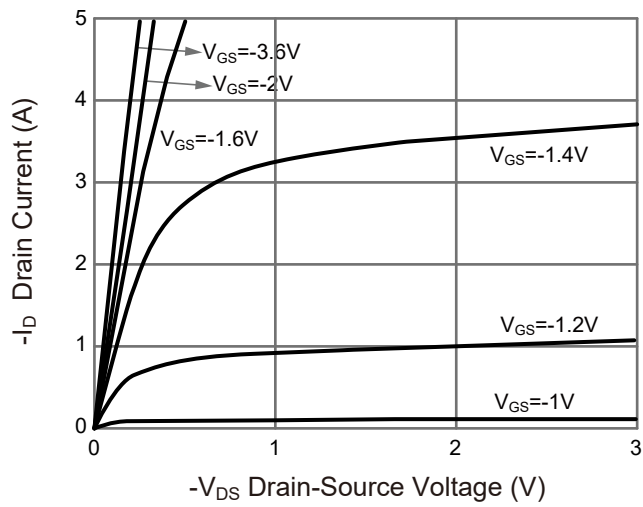
3. Pulse Test: Pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.



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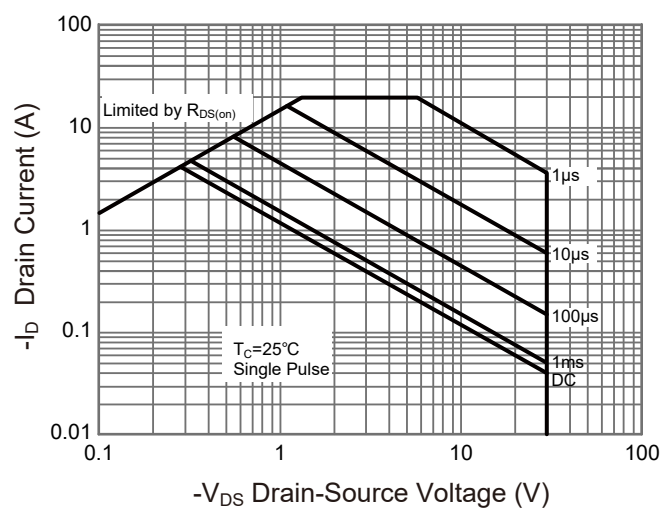
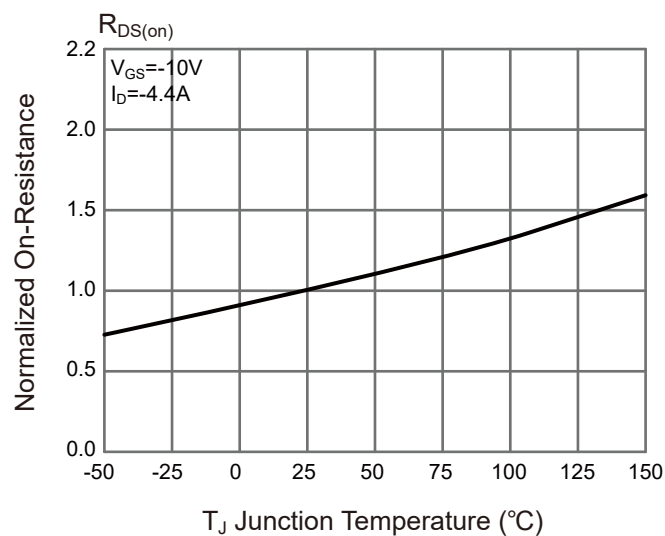
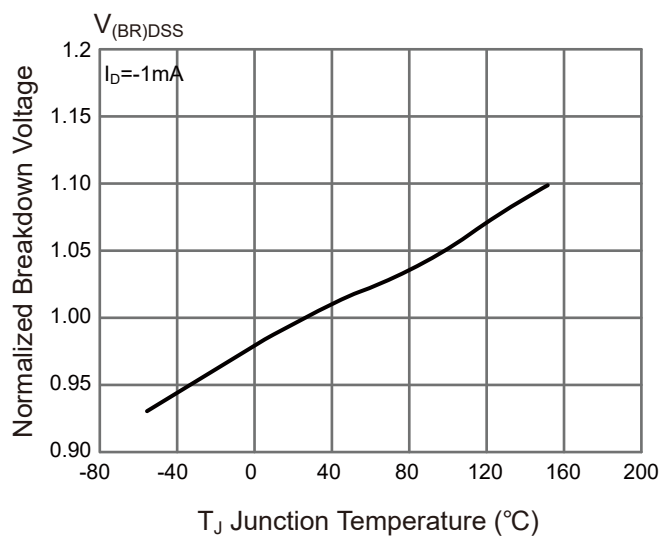
Typical Characteristic Curves





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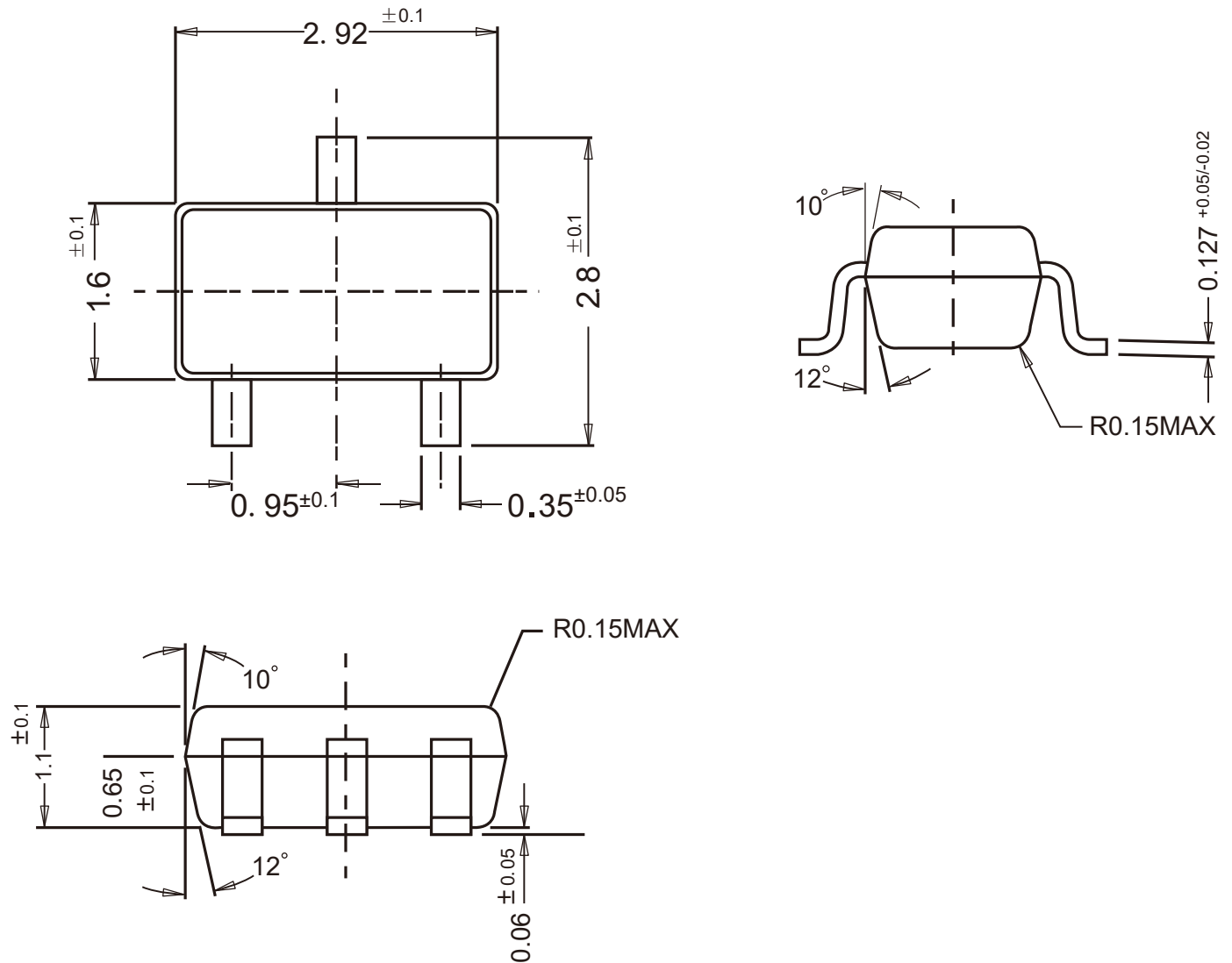
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Package Outline

SOT-23-3

Dimensions in mm



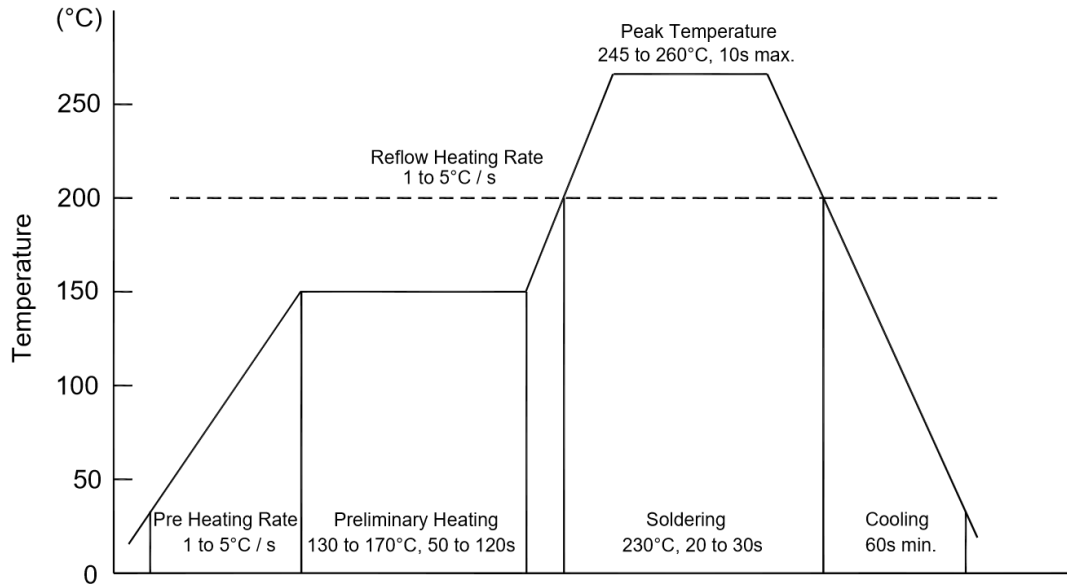
Ordering Information

Device	Package	Shipping
PJM3401PSC	SOT-23-3	3,000PCS/Reel&7inches



Conditions of Soldering and Storage

◆ Recommended condition of reflow soldering



Recommended peak temperature is over 245°C. If peak temperature is below 245°C, you may adjust the following parameters:

- Time length of peak temperature (longer)
- Time length of soldering (longer)
- Thickness of solder paste (thicker)

◆ Conditions of hand soldering

- Temperature: 300°C
- Time: 3s max.
- Times: one time

◆ Storage conditions

- **Temperature**
5 to 40°C
- **Humidity**
30 to 80% RH
- **Recommended period**
One year after manufacturing

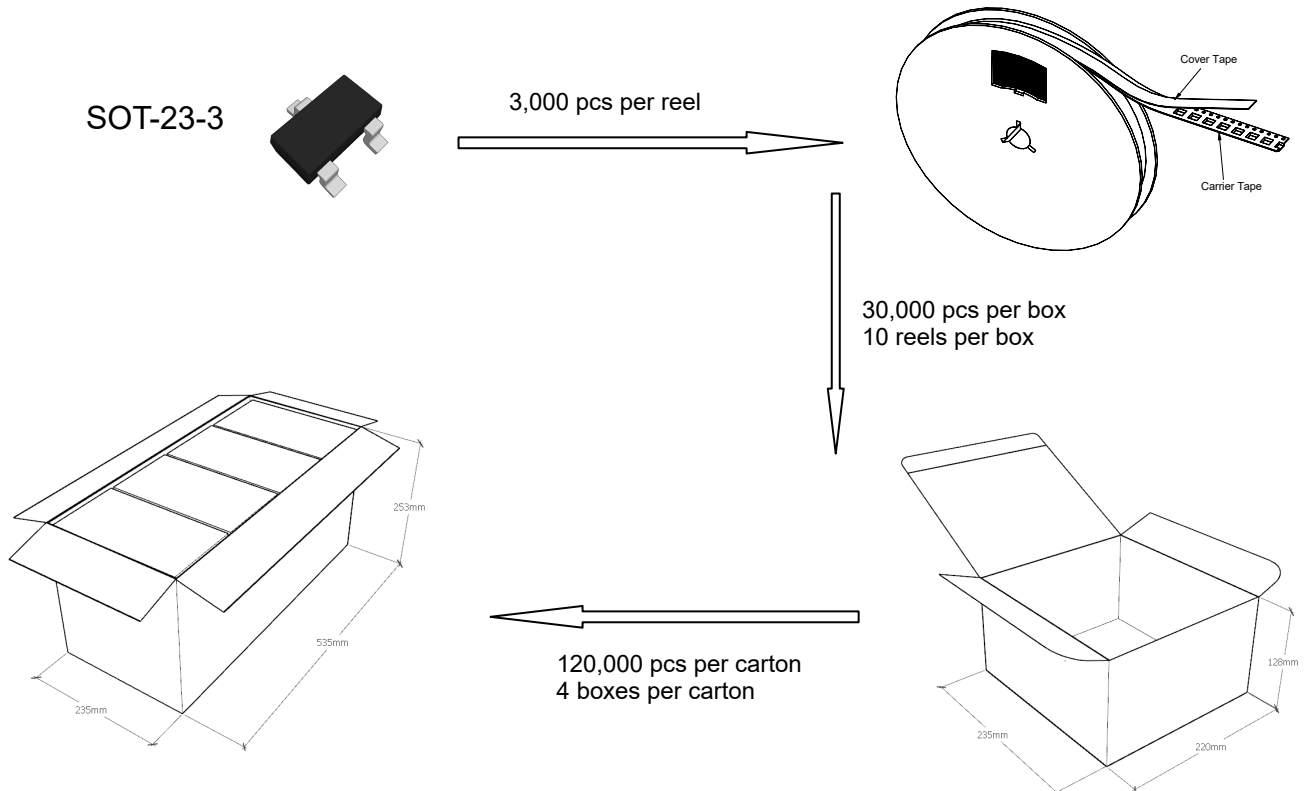


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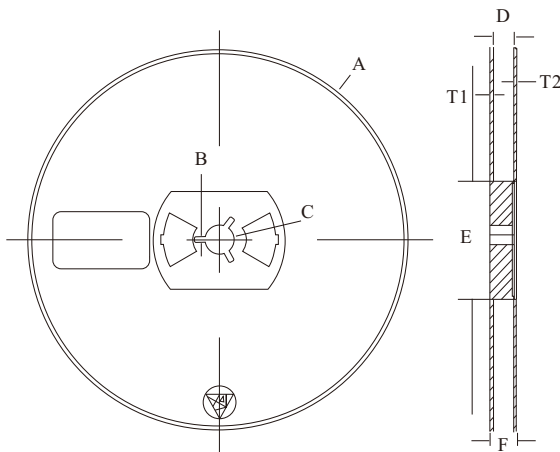
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Package Specifications

- The method of packaging



◆ Embossed tape and reel data



Symbol	Value (unit: mm)
A	Ø 177.8±1
B	2.7±0.2
C	Ø 13.5±0.2
E	Ø 54.5±0.2
F	12.3±0.3
D	9.6+2/-0.3
T1	1.0±0.2
T2	1.2±0.2

Reel (7")

